

COMPLIANT

Low-Voltage Dual SPST Analog Switch

DESCRIPTION

The DG9262/9263 is a single-pole/single-throw monolithic CMOS analog device designed for high performance switching of analog signals. Combining low power, high speed ($_{tON}$: 35 ns, $_{tOFF}$: 20 ns), low on-resistance ($_{tDS(on)}$: 40 $_{tOS}$) and small physical size, the DG9262/9263 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG9262/9263 is built on Vishay Siliconix's low voltage BCD-15 process. Minimum ESD protection, per Method 3015.7 is 2000 V. An epitaxial layer prevents latchup. Break-before make is guaranteed for DG9262/9263.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

BENEFITS

- Reduced Power Consumption
- · Simple Logic Interface
- High Accuracy
- · Reduce Board Space

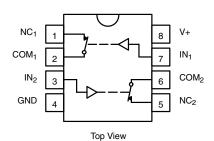
FEATURES

- Low Voltage Operation (+ 2.7 to + 5 V)
- Low On-Resistance $r_{DS(on)}$: 40 Ω
- Fast Switching t_{ON}: 35 ns, t_{OFF}: 20 ns
- Low Leakage I_{COM(on)}: 200-pA max
- Low Charge Injection Q_{IN.I}: 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- ESD Protection > 2000 V (Method 3015.7)
- Available in MSOP-8 and SOIC-8

APPLICATIONS

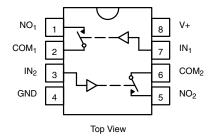
- · Battery Operated Systems
- Portable Test Equipment
- · Sample and Hold Circuits
- · Cellular Phones
- Communication Systems
- · Military Radio
- · PBX, PABX Guidance and Control Systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE - DG9262			
Logic	Switch		
0	On		
1	Off		

Logic "0" \leq 0.8 V Logic "1" \geq 2.4 V



TRUTH TABLE - DG9263				
Logic	Switch			
0	Off			
1	On			

 $\label{eq:logic 00} \begin{array}{l} \text{Logic "0"} \leq 0.8 \ V \\ \text{Logic "1"} \geq 2.4 \ V \end{array}$

ORDERING INFORMATION		
Temp Range	Package	Part Number
- 40 to 85 °C	2010 0	DG9262DY DG9262DY-E3 DG9262DY-T1 DG9262DY-T1-E3
	SOIC-8	DG9263DY DG9263DY-E3 DG9263DY-T1 DG9263DY-T1-E3
	MSOP-8	DG9262DQ-T1-E3
	MSOF-0	DG9263DQ-T1-E3

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply



ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
Reference V+ to GND	- 0.3 to + 13	V			
IN, COM, NC, NO ^a	- 0.3 to (V+ + 0.3)	¬			
Continuous Current (Any Terminal)	± 20	mA			
Peak Current (Pulsed at 1 ms, 10 % dut	± 40				
ESD (Method 3015.7)		> 2000	V		
Storage Temperature (D Suffix)		- 65 to 125	°C		
Power Dissipation (Packages) ^b	8-Pin Narrow Body SOIC ^c	400	mW		

Notes:

- a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board. c. Derate 6.5 mW/ $^{\circ}$ C above 75 $^{\circ}$ C.

Parameter		Test Conditions Unless Otherwise Specified		D Suffix - 40 to 85 °C			
	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.8 \text{ or } 2.4 V^{e}$	Temp ^a	Min ^b	Typ ^c	Max ^b	Unit
Analog Switch	•						
Analog Signal Range ^d	V _{ANALOG}		Full	0		3	V
Drain-Source On-Resistance	r _{DS(on)}	V_{NO} or $V_{NC} = 1.5 \text{ V}, V_{+} = 2.7 \text{ V}$ $I_{COM} = 5 \text{ mA}$	Room Full		50	80 140	Ω
r _{DS(on)} Match ^d	$\Delta r_{DS(on)}$	V _{NO} or V _{NC} = 1.5 V	Room		0.4	2	
r _{DS(on)} Flatness ^d	r _{DS(on)} Flatness	V_{NO} or $V_{NC} = 1$ and 2 V	Room		4	8	
NO or NC Off Leakage Current ^g	I _{NO/NC(off)}	V_{NO} or V_{NC} = 1 V/2 V, V_{COM} = 2 V/1 V	Room Full	- 100 - 5000	5	100 5000	pA
COM Off Leakage Current ^g	I _{COM(off)}	$V_{COM} = 1 \text{ V/2 V}, V_{NO} \text{ or } V_{NC} = 2 \text{ V/1 V}$	Room Full	- 100 - 5000	5	100 5000	
Channel-On Leakage Current ^g	I _{COM(on)}	$V_{COM} = V_{NO}$ or $V_{NC} = 1 \text{ V/2 V}$	Room Full	- 200 - 10000	10	200 10000	
Digital Control			•				•
Input Current	I _{INL} or I _{INH}		Full		1		μΑ
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 1.5 V	Room Full		50	120 200	ns
Turn-Off Time	t _{OFF}	VNO OF VNC = 1.0 V	Room Full		20	50 120	115
Charge Injection ^d	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		1	5	рC
Off-Isolation	OIRR	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room		- 74		dB
Crosstalk	X _{TALK}	π = 30 32, Θ = 3 βι , ι = 1 Ινιι 12	Room		- 90		ub
NC and NO Capacitance	C _(off)	f = 1 MHz	Room		7		
Channel-On Capacitance	C _{COM(on)}		Room		20		pF
COM-Off Capacitance	C _{COM(off)}		Room		13		
Power Supply	1					•	
Power Supply Range	V+			2.7		12	V
Power Supply Current	l+	$V+ = 3.3 \text{ V}, V_{IN} = 0 \text{ or } 3.3 \text{ V}$	<u>-</u>			1	μA

Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
 b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing. d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function. f. Difference of min and max values.
- g. Guraranteed by 5 V leakage testing, not production tested.



		Test Conditions Unless Otherwise Specified		D Suffix - 40 to 85 °C			
Parameter	Symbol	$V+ = 5 V$, $\pm 10 \%$, $V_{IN} = 0.8 \text{ or } 2.4 V^e$	Temp ^a	Min ^b	Typ ^c	Max ^b	Unit
Analog Switch	-		·				
Analog Signal Range ^d	V _{ANALOG}		Full	0		5	V
Drain-Source On-Resistance	r _{DS(on)}	V_{NO} or $V_{NC} = 3.5 \text{ V}, V_{+} = 4.5 \text{ V}$ $I_{COM} = 5 \text{ mA}$	Room Full		30	60 75	
r _{DS(on)} Match ^d	$\Delta r_{DS(on)}$	V_{NO} or $V_{NC} = 3.5 \text{ V}$	Room		0.4	2	Ω
r _{DS(on)} Flatness ^f	DS(on) Flatness	V_{NO} or $V_{NC} = 1$, 2 and 3 V	Room		2	6	
NO or NC Off Leakage Current	I _{NO/NC(off)}	V_{NO} or V_{NC} = 1 V/4 V, V_{COM} = 4 V/1 V	Room Full	- 100 - 5000	10	100 5000	pA
COM Off Leakage Current	I _{COM(off)}	$V_{COM} = 1 \text{ V/4 V}, V_{NO} \text{ or } V_{NC} = 4 \text{ V/1 V}$	Room Full	- 100 - 5000	10	100 5000	
Channel-On Leakage Current	I _{COM(on)}	$V_{COM} = V_{NO}$ or $V_{NC} = 1 \text{ V/4 V}$	Room Full	- 200 - 10000		200 10000	
Digital Control	•					•	
Input Current	I _{INL} or I _{INH}		Full		1		μΑ
Dynamic Characteristics	·						
Turn-On Time	t _{ON}	V_{NO} or $V_{NC} = 3.0 \text{ V}$	Room Full		35	75 150	ns
Turn-Off Time	t _{OFF}		Room Full		20	50 100	7 118
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega$	Room		2	5	рС
Off-Isolation	OIRR	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room		- 74		٩D
Crosstalk	X _{TALK}	$n_L = 50.52, O_L = 5 \text{ pr}, I = 1 \text{ M/Hz}$	Room		- 90		dB
NC and NO Capacitance	C _(off)	f = 1 MHz	Room		7		
Channel-On Capacitance	C _{D(on)}		Room		20		pF
COM-Off Capacitance	C _{COM(off)}		Room		13		
Power Supply						•	
Power Supply Range	V+			2.7		12	V
Power Supply Current	I+	V+ = 5.5 V, V _{IN} = 0 or 5.5 V				1	μΑ

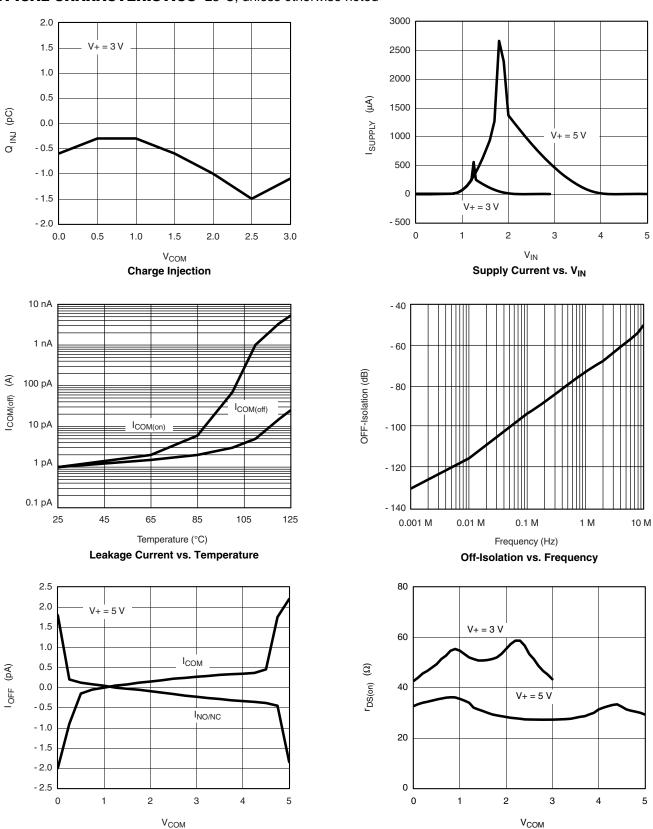
Notes:

- a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Difference of min and max values.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS 25°C, unless otherwise noted



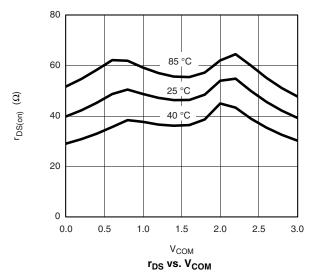
Off-Leakage vs. Voltage at 25 °C

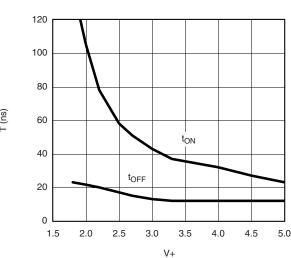
 r_{DS} vs. V_{COM}



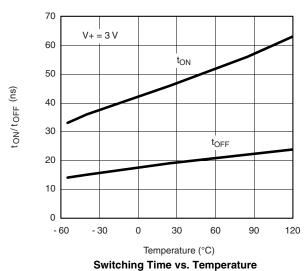


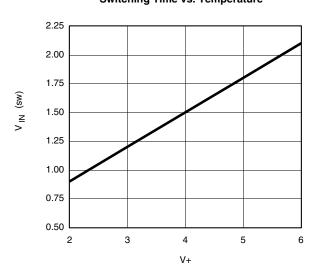
TYPICAL CHARACTERISTICS 25°C, unless otherwise noted





 $t_{\mbox{\scriptsize ON}}/t_{\mbox{\scriptsize OFF}}$ vs. Power Supply Voltage





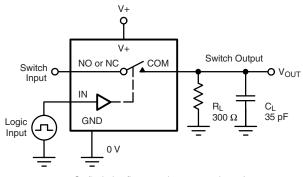
VISHAY.

t_r < 20 ns

t_f < 20 ns

0.9 x V_{OUT}

TEST CIRCUITS



t_{ON} –

+ 3 V

0 V

0 V

Logic Input

Switch Output

> Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

50 %

 \mathbf{C}_{L} (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Figure 1. Switching Time

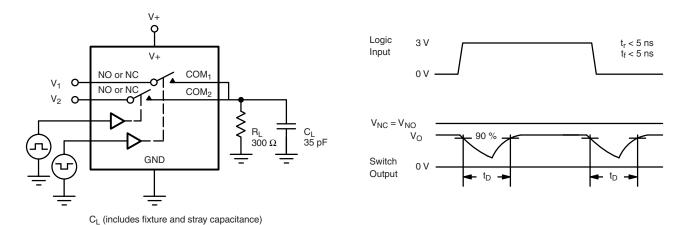


Figure 2. Break-Before-Make Interval

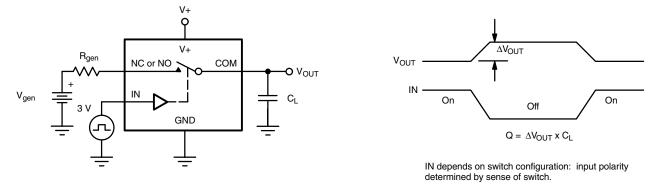


Figure 3. Charge Injection



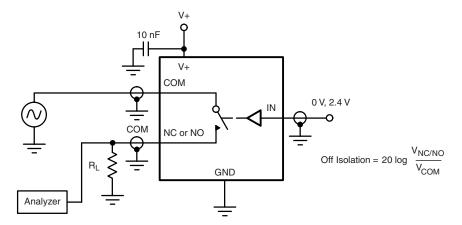


Figure 4. Off-Isolation

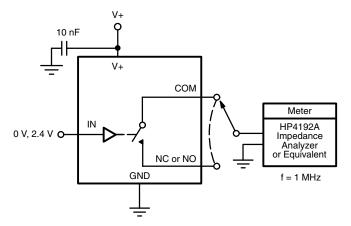


Figure 5. Channel Off/On Capacitance

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